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	Substitute for	Form 1449A/PTO		Application Number	TBD				
	INFORMATIO	N DISCLOSURE		Filing Date	Herewith				
		BY APPLICANT		First Named Inventor	Srinivasan Chakravarthi, et al.				
	STATEMENT	DI AITEIOAITI		Group Art Unit	2813				
	(use as many sl	heets as necessary)		Examiner Name	Yennhu B. Huyh				
Sheet	1	of	1	Attorney Docket No.	TI-33161.1				

				U.S. I	PATENT DOCUME	ENTS
		U.S. Patent D	Document	Name of Patentee	Date of Pub.	
Exam. Initials*	Cite No. ¹	Number	Kind Code ² (if known)	or Applicant of Cited Doc.	of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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	AB					
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	FOREIGN PATENT DOCUMENTS								
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	OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS					
Exam. Initials*			T²			
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